

SCCS062B - August 1994 - Revised September 2001

# 18-Bit Registers

#### **Features**

- Ioff supports partial-power-down mode operation
- Edge-rate control circuitry for significantly improved noise characteristics
- Typical output skew < 250 ps</li>
- ESD > 2000V
- TSSOP (19.6-mil pitch) and SSOP (25-mil pitch) packages
- Industrial temperature range of -40°C to +85°C
- $V_{CC} = 5V \pm 10\%$

#### CY74FCT16823T Features:

- · 64 mA sink current, 32 mA source current
- Typical  $V_{OLP}$  (ground bounce) <1.0V at  $V_{CC}$  = 5V,  $T_A$  = 25°C

#### CY74FCT162823T Features:

- · Balanced 24 mA output drivers
- · Reduced system switching noise
- Typical V<sub>OLP</sub> (ground bounce) <0.6V at V<sub>CC</sub> = 5V, TA = 25°C

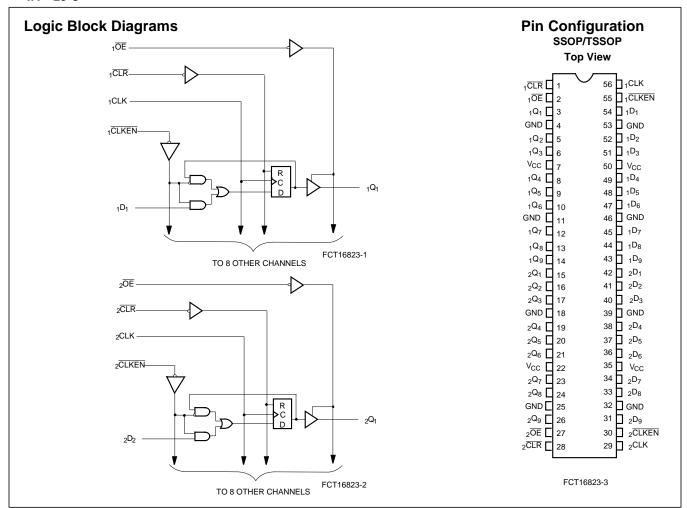
#### **Functional Description**

The CY74FCT16823T and the CY74FCT162823T 18-bit bus interface registers are designed for use in high-speed, low-power systems needing wide registers and parity. 18-bit operation is achieved by connecting the control lines of the two 9-bit registers. Flow-through pinout and small shrink packaging aids in simplifying board layout.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The CY74FCT16823T is ideally suited for driving high-capacitance loads and low-impedance backplanes.

The CY74FCT162823T has 24-mA balanced output drivers with current limiting resistors in the outputs. This reduces the need for external terminating resistors and provides for minimal undershoot and reduced ground bounce. The CY74FCT162823T is ideal for driving transmission lines.





#### **Pin Description**

Name	Description
D	Data Inputs
CLK	Clock Inputs
CLKEN	Clock Enable Inputs (Active LOW)
CLR	Asynchronous Clear Inputs (Active LOW)
ŌĒ	Output Enable Inputs (Active LOW)
Q	Three-State Outputs

#### Function Table<sup>[1]</sup>

	Inputs					
ŌĒ	CLR	CLKEN	CLK	D	Q	Function
Н	Х	Х	Х	Χ	Z	High Z
L	L	Х	Х	Х	L	Clear
L	Н	Н	Х	Х	Q <sup>[2]</sup>	Hold
Н	Н	L	Т	L	Z	Load
Н	Н	L	Т	Н	Z	
L	Н	L	Т	L	L	
L	Н	L	Т	Н	Н	

# Maximum Ratings<sup>[3, 4]</sup>

(Above which the useful life may guidelines, not tested.)	be impaired. For user
Storage Temperature	55°C to +125°C
Ambient Temperature with Power Applied	55°C to +125°C
DC Input Voltage	0.5V to +7.0V
DC Output Voltage	0.5V to +7.0V
DC Output Current (Maximum Sink Current/Pin)	60 to +120 mA

Power Dissipation	1.0W
Static Discharge Voltage	>2001V
(per MIL-STD-883, Method 3015)	

# **Operating Range**

Range	Ambient Temperature	V <sub>CC</sub>
Industrial	–40°C to +85°C	5V ± 10%

#### Notes:

- H = HIGH Voltage Level.
   L = LOW Voltage Level.
   X = Don't Care.
   Z = HIGH Impedance.
- T=LOW-to-HIGH transition.

  Output level before indicated steady-state input conditions were established.

  Operation beyond the limits set forth may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range.

  Unused inputs must always be connected to an appropriate logic voltage level, preferably either V<sub>CC</sub> or ground.



#### **Electrical Characteristics** Over the Operating Range

Parameter	Description	Test Conditions	Min.	<b>Typ.</b> <sup>[5]</sup>	Max.	Unit
V <sub>IH</sub>	Input HIGH Voltage		2.0			V
V <sub>IL</sub>	Input LOW Voltage				0.8	V
V <sub>H</sub>	Input Hysteresis <sup>[6]</sup>			100		mV
V <sub>IK</sub>	Input Clamp Diode Voltage	V <sub>CC</sub> =Min., I <sub>IN</sub> =-18 mA		-0.7	-1.2	V
I <sub>IH</sub>	Input HIGH Current	V <sub>CC</sub> =Max., V <sub>I</sub> =V <sub>CC</sub>			±1	μΑ
I <sub>IL</sub>	Input LOW Current	V <sub>CC</sub> =Max., V <sub>I</sub> =GND			±1	μΑ
I <sub>OZH</sub>	High Impedance Output Current (Three-State Output pins)	V <sub>CC</sub> =Max., V <sub>OUT</sub> =2.7V			±1	μА
I <sub>OZL</sub>	High Impedance Output Current (Three-State Output pins)	V <sub>CC</sub> =Max., V <sub>OUT</sub> =0.5V			±1	μΑ
Ios	Short Circuit Current <sup>[7]</sup>	V <sub>CC</sub> =Max., V <sub>OUT</sub> =GND	-80	-140	-200	mA
I <sub>O</sub>	Output Drive Current <sup>[7]</sup>	V <sub>CC</sub> =Max., V <sub>OUT</sub> =2.5V	-50		-180	mA
I <sub>OFF</sub>	Power-Off Disable	V <sub>CC</sub> =0V, V <sub>OUT</sub> ≤4.5V <sup>[8]</sup>			1	μΑ

#### **Output Drive Characteristics for CY74FCT16823T**

Parameter	Description	Test Conditions	Min.	<b>Typ.</b> <sup>[5]</sup>	Max.	Unit
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> =Min., I <sub>OH</sub> =-3 mA	2.5	3.5		V
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-15 mA	2.4	3.5		
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-32 mA	2.0	3.0		
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> =Min., I <sub>OL</sub> =64 mA		0.2	0.55	V

#### **Output Drive Characteristics for CY74FCT162823T**

Parameter	Description	Test Conditions	Min.	<b>Typ.</b> <sup>[5]</sup>	Max.	Unit
I <sub>ODL</sub>	Output LOW Voltage <sup>[7]</sup>	V <sub>CC</sub> =5V, V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> =1.5V	60	115	150	mA
I <sub>ODH</sub>	Output HIGH Voltage <sup>[7]</sup>	$V_{CC}$ =5V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ , $V_{OUT}$ =1.5V	-60	-115	-150	mA
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> =Min., I <sub>OH</sub> =-24 mA	2.4	3.3		V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> =Min., I <sub>OL</sub> =24 mA		0.3	0.55	V

# **Capacitance**[9] $(T_A = +25^{\circ}C, f = 1.0 \text{ MHz})$

Parameter	Description	Test Conditions	<b>Typ.</b> <sup>[5]</sup>	Max.	Unit
C <sub>IN</sub>	Input Capacitance	$V_{IN} = 0V$	4.5	6.0	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V	5.5	8.0	pF

- Typical values are at V<sub>CC</sub>= 5.0V, T<sub>A</sub>= +25°C ambient.
   This input is specified but not tested.
   Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>O</sub> set sets should be performed last.
- 8. Tested at +25°C.
  9. This parameter is specified but not tested.



#### **Power Supply Characteristics**

Parameter	Description	Test Condit	ions <sup>[10]</sup>	Min.	Typ. <sup>[5]</sup>	Max.	Unit
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>CC</sub> =Max.	V <sub>IN</sub> ≤0.2V V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	_	5	500	μΑ
Δl <sub>CC</sub>	Quiescent Power Supply Current (TTL inputs HIGH)	V <sub>CC</sub> =Max.	V <sub>IN</sub> =3.4V <sup>[11]</sup>	_	0.5	1.5	mA
I <sub>CCD</sub>	Dynamic Power Supply Current <sup>[12]</sup>	V <sub>CC</sub> =Max., One Input Toggling, 50% Duty Cycle, Outputs Open, OE=CLKEN=GND	V <sub>IN</sub> =V <sub>CC</sub> or V <sub>IN</sub> =GND	_	75	120	μΑ/ MHz
I <sub>C</sub>		f <sub>0</sub> =10 MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling, OE=CLKEN=GND at f <sub>1</sub> =5 MHz V <sub>CC</sub> =Max., at f <sub>1</sub> =2.5 MHz,	V <sub>IN</sub> =V <sub>CC</sub> or V <sub>IN</sub> =GND	_	0.8	1.7	mA
			V <sub>IN</sub> =3.4V or V <sub>IN</sub> =GND	_	1.3	3.2	
			V <sub>IN</sub> =V <sub>CC</sub> or V <sub>IN</sub> =GND	_	4.2	7.1 <sup>[14]</sup>	
	50% Duty Cycle, Outputs Open, Eighteen Bits Toggling, OE=CLKEN=GND f <sub>0</sub> =10 MHz	V <sub>IN</sub> =3.4V or V <sub>IN</sub> =GND	_	9.2	22.1 <sup>[14]</sup>		

Notes:
10. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
11. Per TTL driven input (V<sub>IN</sub>=3.4V); all other inputs at V<sub>CC</sub> or GND.
12. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
13. I<sub>C</sub> = I<sub>QUIESCENT</sub> + I<sub>INPUTS</sub> + I<sub>DYNAMIC</sub> I<sub>C</sub> = I<sub>CC</sub>+ΔI<sub>CC</sub>D<sub>H</sub>N<sub>T</sub>+I<sub>CCD</sub>(f<sub>0</sub>/2 + f<sub>1</sub>N<sub>1</sub>) I<sub>CC</sub> = Quiescent Current with CMOS input levels

 $\begin{array}{lll} I_C &=& I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} U_{0/2} + \dots \\ I_{CC} &=& Quiescent Current with CMOS input levels \\ \Delta I_{CC} &=& Power Supply Current for a TTL HIGH input (<math>V_{IN}$ =3.4V) \\ D\_H &=& Duty Cycle for TTL inputs HIGH \\ &=& Consistion pair (HLf) \\ \end{array}

BH = Duty Cycle for TTL injuts FIGH

N<sub>T</sub> = Number of TTL injuts at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic Current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Injut signal frequency

T<sub>1</sub> = Input signal frequency
 N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>
 All currents are in milliamps and all frequencies are in megahertz.
 14. Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are specified but not tested.



# **Switching Characteristics** Over the Operating Range<sup>[15]</sup>

				CY74FCT16823AT CY74FCT162823AT		
Parameter	Description	Condition <sup>[16]</sup>	Min.	Max.	Unit	Fig.No. <sup>[16]</sup>
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay CLK to Q	$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	10.0	ns	1, 5
		$C_L = 300 \text{ pF}^{[17]}$ $R_L = 500\Omega$	1.5	20.0		
t <sub>PHL</sub>	Propagation Delay CLR to Q	$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	14.0	ns	1, 5
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time OE to Q	$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	12.0	ns	1, 7, 8
		$C_L = 300 \text{ pF}^{[17]}$ $R_L = 500\Omega$	1.5	23.0		
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time OE to Q	$C_L=5 \text{ pF}^{[17]} \ R_L=500\Omega$	1.5	7.0	ns	1, 7, 8
		$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	8.0		
t <sub>SU</sub>	Set-Up Time HIGH or LOW, D to CLK	C <sub>L</sub> =50 pF	3.0	_	ns	4
t <sub>H</sub>	Hold Time HIGH or LOW, D to CLK	$R_L^-=500\Omega$	1.5	_	ns	4
t <sub>SU</sub>	Set-Up Time HIGH or LOW, CLKEN to CLK		3.0	_	ns	9
t <sub>H</sub>	Hold Time HIGH or LOW CLKEN to CLK		0.0	_	ns	9
t <sub>W</sub>	CLK Pulse Width HIGH or LOW		6.0	_	ns	5
t <sub>W</sub>	CLR Pulse Width LOW		6.0	_	ns	5
t <sub>REM</sub>	Recovery Time CLR to CLK		6.0	_	ns	6
t <sub>SK(O)</sub>	Output Skew <sup>[18]</sup>		_	0.5	ns	_

# Switching Characteristics Over the Operating Range<sup>[15]</sup>

			CY74FCT16823CT CY74FCT162823CT			
Parameter	Description	Condition <sup>[16]</sup>	Min.	Max.	Unit	Fig.No. <sup>[16]</sup>
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay CLK to Q	$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	6.0	ns	1, 5
		$C_L = 300 \text{ pF}^{[17]}$ $R_L = 500\Omega$	1.5	12.5		
t <sub>PHL</sub>	Propagation Delay CLR to Q	$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	6.1	ns	1, 5
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time  OE to Q	$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	5.5	ns	1, 7, 8
		$C_L = 300 \text{ pF}^{[17]}$ $R_L = 500\Omega$	1.5	12.5		
t <sub>PHZ</sub>	Output Disable Time OE to Q	$C_L=5 \text{ pF}^{[17]} \ R_L=500\Omega$	1.5	5.2	ns	1, 7, 8
		$C_L$ =50 pF $R_L$ =500 $\Omega$	1.5	6.5		



# **Switching Characteristics** Over the Operating Range<sup>[15]</sup> (continued)

			CY74FCT CY74FCT1			
Parameter	Description	Condition <sup>[16]</sup>	Min.	Max.	Unit	Fig.No. <sup>[16]</sup>
t <sub>SU</sub>	Set-Up Time HIGH or LOW, D to CLK	$C_L$ =50 pF $R_L$ =500 $\Omega$	2.0	_	ns	4
t <sub>H</sub>	Hold Time HIGH or LOW, D to CLK		1.5	_	ns	4
t <sub>SU</sub>	Set-Up Time HIGH or LOW, CLKEN to CLK		3.0	_	ns	9
t <sub>H</sub>	Hold Time HIGH or LOW CLKEN to CLK		0.0	_	ns	9
t <sub>W</sub>	CLK Pulse Width HIGH or LOW		3.3	_	ns	5
t <sub>W</sub>	CLR Pulse Width LOW		3.3	_	ns	5
t <sub>REM</sub>	Recovery Time CLR to CLK		6.0	_	ns	6
t <sub>SK(O)</sub>	Output Skew <sup>[18]</sup>		_	0.5	ns	_

#### Notes:

- Minimum limits are specified but not tested on Propagation Delays.
   See "Parameter Measurement Information" in the General Information section.
   These limits are specified but not tested.
   Skew between any two outputs of the same package switching in the same direction. This parameter is ensured by design.

# **Ordering Information CY74FCT16823**

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
6.0	CY74FCT16823CTPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT16823CTPVC/PVCT	O56	56-Lead (300-Mil) SSOP	
10.0	CY74FCT16823ATPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial

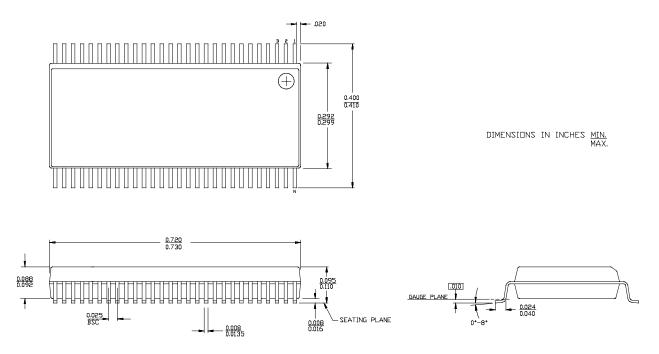
# **Ordering Information CY74FCT162823**

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
6.0	74FCT162823CTPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT162823CTPVC	O56	56-Lead (300-Mil) SSOP	
	74FCT162823CTPVCT	O56	56-Lead (300-Mil) SSOP	
10.0	74FCT162823ATPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial

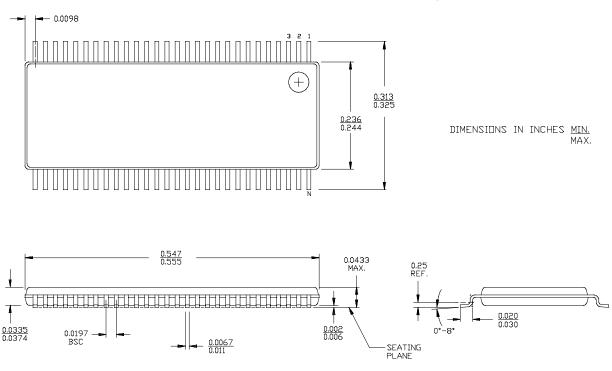


# **Package Diagrams**

#### 56-Lead Shrunk Small Outline Package O56



#### 56-Lead Thin Shrunk Small Outline Package Z56





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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
CY74FCT16823ATPACT	OBSOLETE	TSSOP	DGG	56		TBD	Call TI	Call TI	-40 to 85	FCT16823A	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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